TOSHIBA Bipolar Linear Integrated Circuit Silicon Monolithic

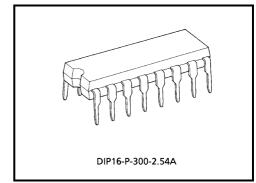
TA8142AP

Rec / Play Pre Amp System For Double Cassette

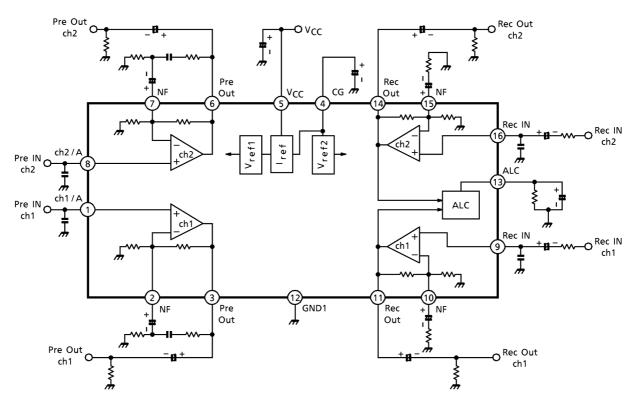
The TA8142AP is a quad pre amplifier designed for use in record / play back pre amplifier of tape recorder. It is suitable for a double radio cassette recorder.

Features

- Built in play back amplifier
- Built in recording amplifier
- ALC detector circuit
- Operating supply voltage range : V_{CC} (opr) = 4~13.5V (Ta = 25°C)



Weight: 1.00g (typ.)



Block Diagram

Maximum Ratings (Ta = 25°C)

Characteristic	Symbol	Rating	Unit	
Supply voltage	V _{CC}	14.5	V	
Power dissipation	P _D (Note)	750	mW	
Operating temperature	T _{opr}	-20~75	°C	
Storage temperature	T _{stg}	-55~150	°C	

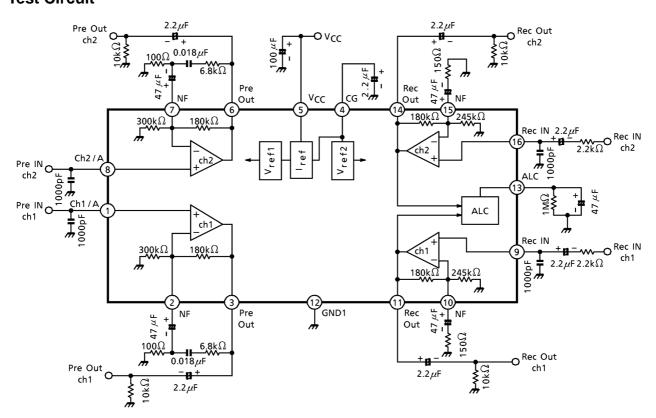
(Note) Derated above Ta = 25° C in the proportion of 6mW / °C.

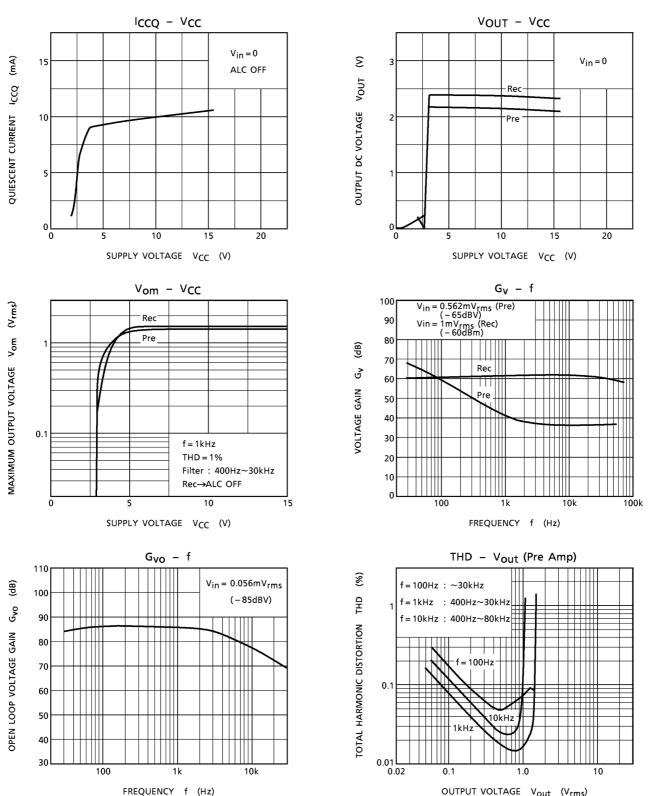
Electrical Characteristics (unless otherwise specified, V_{CC} = 6V, f = 1kHz, B.P.F = 400Hz~30kHz)

	Characteristic	Symbol	Test Cir– cuit	Test Condition	Min.	Тур.	Max.	Unit
Quiescent current		I _{ccq}	_	—	_	9.5	15	mA
.qr	Output noise voltage	V _{no} (pre)	_	Normal mode, R _g = 2.2kΩ, NAB EQ BW = 20Hz~20kHz, G _v = 40dB	_	150	350	μV _{rms}
	Total harmonic distortion	THD (pre)	_	V _{out} = 0.2V _{rms} , f = 1kHz normal mode	_	0.05	0.1	%
	Maximum output voltage	V _{om} (pre)	_	THD = 1.0%, R _L = 10kΩ, f = 1kHz normal mode	0.9	1.4	_	V _{rms}
Back Amp.	Open loop voltage gain	G _{vo} (pre)	_	f = 1kHz, R _L = 10kΩ V _{in} = 13.8μV _{rms} (–95dBV)	80	93	_	dB
Play E	Cross talk	C.T. (ch) (pre)	_	$V_{out} = 0.775V_{rms}$ (0dBm), f = 1kHz R _g = 2.2k Ω , normal mode	-70	-77	_	dB
	Ripple rejection ratio	R.R. (pre)	_	Vripple = $0.775V_{rms}$ (0dBm) fripple = 100Hz, normal mode R _g = 2.2kΩ, LPF = ~30kHz	_	-40	_	dB
	Voltage gain	G _{vn} (pre)	_	V _{in} = 7.75mV _{rms} (–40dBm) f = 1kHz, normal NAB, R _L = 10kΩ	_	40		dB
Pre amp → rec amp C.T		C.T. (P / R)	_	f = 1kHz, V _{out} (pre) = 0.775V _{rms} (0dBm), normal (pre)	_	-53.5	_	dB
Rec amp → pre amp C.T		C.T. (R / P)	_	f = 1 kHz, V _{out} (rec) = 0.775 V _{rms} (0dBm), normal (pre)	_	-77.5	_	dB
	Output noise level	V _{no} (rec)	_	R _g = 2.2 kΩ, BW = 20 Hz~20 kHz ALC off, G _v = 60dB	_	1.3	2.7	mV _{rms}
Recording Amp.	Total harmonic distortion	THD (rec)	_	$V_{out} = 0.5V_{rms}$, f = 1kHz ALC off, R _L = 10k Ω	_	0.35	0.9	%
	Maximum output level	V _{om} (rec)	_	THD = 1%, R_L = 10k Ω , f = 1kHz ALC off	1.2	1.5	_	V _{rms}
	Open loop voltage gain	G _{vo} (rec)	_	f = 1kHz, R _L = 10kΩ, V _{in} = 3.16 μ V _{rms} (–110dBV)	76	86	_	dB
	ALC range	R (ALC)	_	3dB up	_	50	_	dB

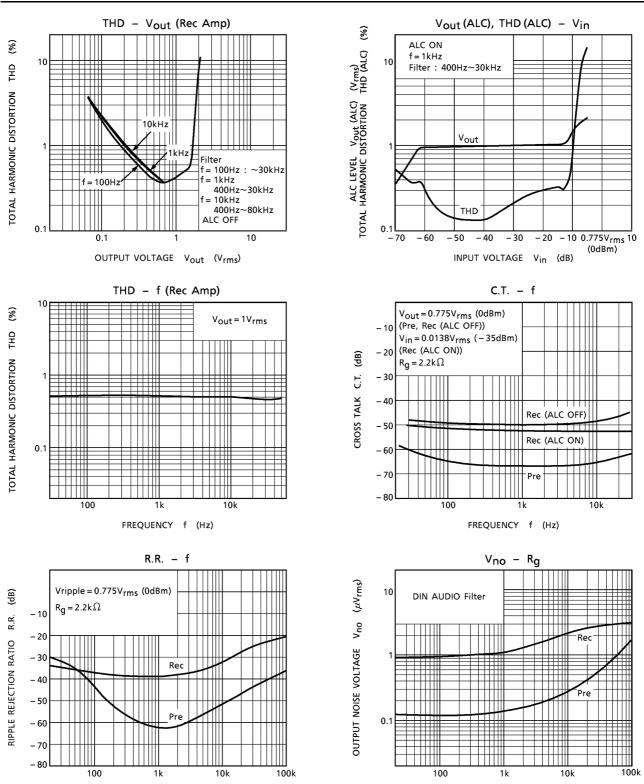
	Characteristic	Symbol	Test Cir– cuit	Test Condition	Min.	Тур.	Max.	Unit
	Total harmonic distortion (ALC)	THD (ALC)	_	V _{in} = 0.0775V _{rms} (–20dBm) f = 1kHz, dual input, R _L = 10kΩ	_	0.3	0.9	%
	ALC balance	B (ALC)	_	V_{in} = 0.0775 V_{rms} (–20dBm) dual input, f = 1kHz, R _L = 10k Ω	-2	0	+2	dB
Amp.	ALC level	V (ALC)	_	V _{in} = 0.0775V _{rms} (–20dBm) f = 1kHz, R _L = 10kΩ	0.75	1.0	1.2	V _{rms}
Recording A	Ripple rejection ratio	R.R. (rec)	_	V _R = 0.775V _{rms} (0dBm), f = 100Hz R _g = 2.2kΩ, LPF = ~30kHz	_	38	_	dB
	Voltage gain	G _{vn} (rec)	_	f = 1kHz (flat), R _L = 10kΩ V _{in} = 1mV _{rms} (–60dBV)	_	61	_	dB
	Cross talk (ALC off)	C.T. (ch)	_	$V_{out} = 0.775V_{rms}$ (0dBm), f = 1kHz R _g = 2.2kΩ, ALC off	40	54	_	dB
	Cross talk (ALC on)	C.T. (ch)	_	f = 1kHz, R _g = 2.2kΩ, ALC on V _{in} = 0.0775V _{rms} (–20dBm)	40	52	_	dB

Test Circuit



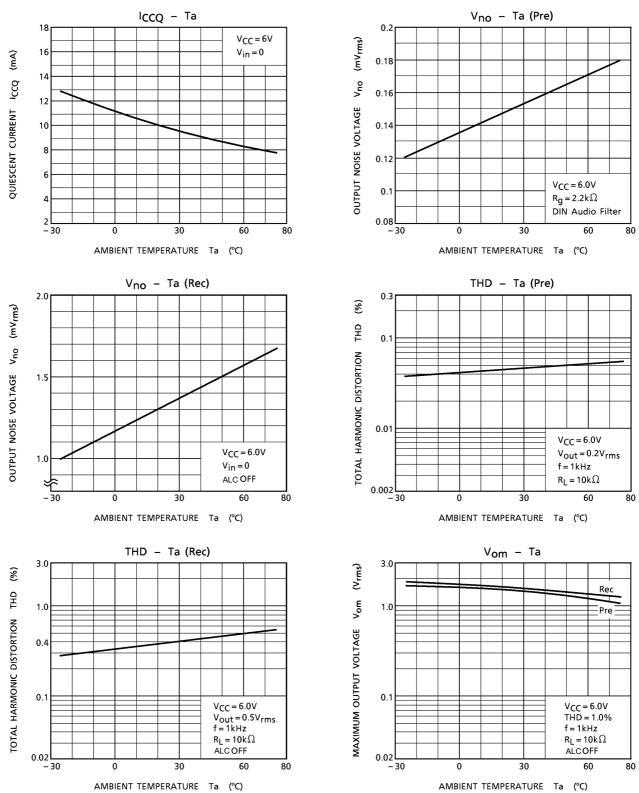


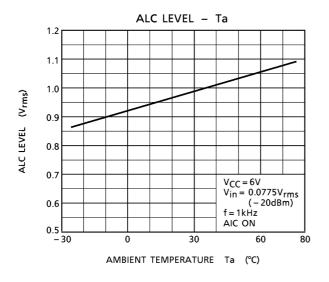
OUTPUT VOLTAGE Vout (Vrms)



SIGNAL SOURCE RESISTANCE R_{g} (Ω)

FREQUENCY f (Hz)

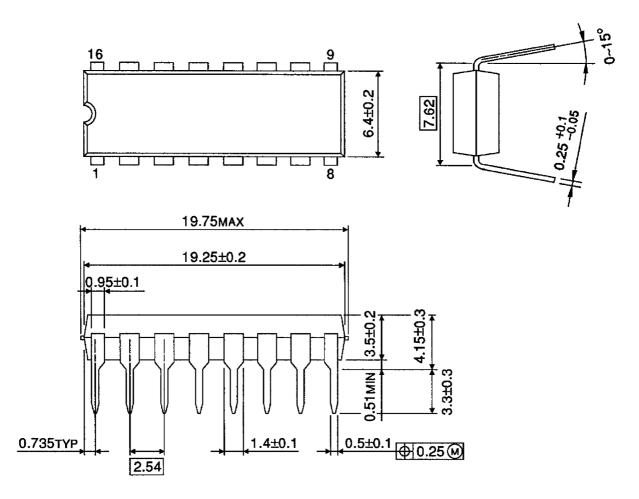




Package Dimensions

DIP16-P-300-2.54A

Unit : mm



Weight: 1.00g (typ.)

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